

Advanced CMOS TTL Input – 54ACT86

Quadruple 2-Input Exclusive OR Gate IC in bare die form

Description

The 54ACT86 exclusive OR gate (XOR) is fabricated using a 1.5µm advanced CMOS process which combines the high speed performance of LSTTL with CMOS low power consumption. This device contains four independent gates and performs the Boolean functions $Y = A \oplus B$ or $Y = \overline{AB} + A\overline{B}$. The device is characterized over the full military temperature range. Device inputs directly accept LSTTL or CMOS. All inputs are protected against ESD and excess voltage transients.

Ordering Information

The following part suffixes apply:

- No suffix MIL-STD-883 /2010B Visual Inspection
- "H" MIL-STD-883 /2010B Visual Inspection + MIL-PRF-38534 Class H LAT
- "K" MIL-STD-883 /2010A Visual Inspection (Space)
 + MIL-PRF-38534 Class K_AT

LAT = Lot Acceptance Test.

For further information on LAT process flows see below.

www.siliconsupplies.com\quality\bare-die-lot-qualification

Supply Formats:

- Defaut Die in Waffle Pack (400 per tray capacity)
- Sawn Wafer on Tape On request
- Unsawn Wafer On request
- Die Thickness <> 350µm(14 Mils) On request
- Assembled into Ceramic Package On request

Features:

- Inputs directly accept TTL
- Outputs directly interface CMQS_NMOS and TTL

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- Outputs Source/Sink 24 mA
- Low Input Current: 1
- Functionally competible with bipolar 54LS86
- Lower power alternative to bipolar logic
- Full Military Temperature Range

Die Dimensions in µm (mils)

←	1300 (51)	
		1300 (51)

Mechanical Specification

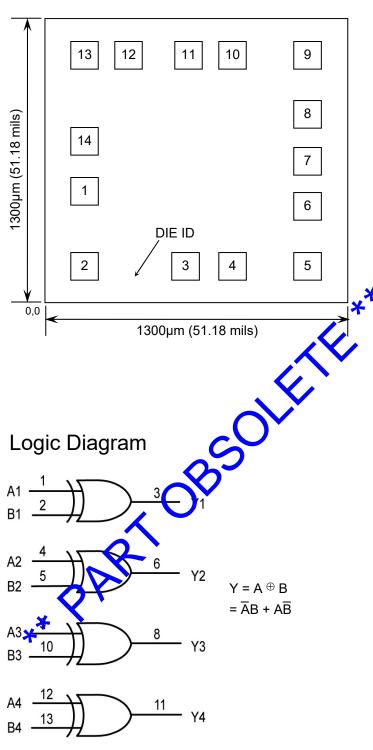
Die Size (Unsawn)	1300 x 1300 51 x 51`	µm mils
Minimum Bond Pad Size	120 x 120 4.72 x 4.72	µm mils
Die Thickness	350 (±20) 13.78 (±0.79)	µm mils
Top Metal Composition	Al 1%Si 1.1µ	m
Back Metal Composition	N/A – Bare S	Si

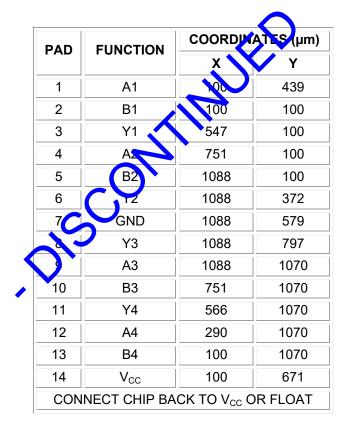




Pad Layout and Functions

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Function Table

INP	UTS	OUTPUT					
Α	В	Y					
L	L	L					
L	Н	H					
Н	L	Н					
Н	Н	L					
H = H	H = High level (steady state)						
L = L	ow leve	el (steady state)					





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Absolute Maximum Ratings¹

PARAMETER	SYMBOL	VALUE	UNIT
DC Supply Voltage (Referenced to GND)	V _{CC}	-0.5 to +7.0	N
DC Input Voltage (Referenced to GND)	V _{IN}	-0.5 to V _{CC} +0.5	
DC Output Voltage (Referenced to GND)	V _{OUT}	-0.5 to V _{CC} +0.5	V
DC Input Current	I _{IN}	±20	mA
DC Output Current, per pad	Ι _{ουτ}	±50	mA
DC Supply Current, V _{CC} or GND, per pad	I _{cc}	±50	mA
Power Dissipation in Still Air ²	PD	750	mW
Storage Temperature Range	T _{STG}	-65 to 150	۵°C

1. Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability. 2. Measured in plastic DIP package, results in die form are dependent on vie attach and assembly method.

Recommended Operating Conditions³ (Voltages Referenced to GND)

	· · · · · ·		,		
PARAMETER	SYMBOL	MIN	MAX	UNITS	
DC Supply Voltage	V _{cc}	4.5	5.5	V	
DC Input or Output Voltage	V _{IN} ,V _{OUT}	X 0	V _{cc}	V	
Operating Temperature Rang	TJ	⊁ -55	+125	°C	
Output current - High	Іон	-	-24	mA	
Output current - Low		-	24	mA	
Input Rise or Fall rate	ΔυΔν	0	10	ns/V	
(V _{IN} from 0.8V to 2V)	V _{CC} = 5.5V		0	8	115/ V

3. This device contains protection circuitry to guard equalst damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than naximum rated voltages to this high-impedance circuit. For proper operation, V_{IN} and V_{OUT} should be constrained to the range GND \leq (V_{IN} or V_{OUT}) = V_{CO} . Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

PARAMETER	STMBOL	V _{cc}	CONDITIONS	LIMITS			UNITS
		VCC	CONDITIONO	25°C	85°C	FULL RANGE ⁴	
Minimum High-Level		4.5V	V _{OUT} = 0.1V	2	2	2	V
Input Voltage		5.5V	or V_{CC} -0.1V	2	2	2	V
Maximum Low-Lovel	VIL	4.5V	V _{OUT} = 0.1V	0.8	0.8	0.8	V
Input volage	VIL	5.5V	or V _{CC} -0.1V	0.8	0.8	0.8	V
×		4.5V	Ι _{ΟυΤ} = 50μΑ	0.1	0.1	0.1	V
*		5.5V		0.1	0.1	0.1	
Minimum Low-Level	V _{OL}	4.5V	$V_{IN} = V_{IL} \text{ or } V_{IH}^{5}$	0.36	0.44	0.50	V
Output Voltage	VOL	5.5V	$I_{OL} = 24mA$	0.36	0.44	0.50	v
	4.5V	$V_{IN} = V_{IL} \text{ or } V_{IH}^{5,6}$	-	-	1.65	V	
	5.5V	I _{OL} = 50mA	-	-	1.65	V V	

DC Electrical Characteristics (Voltages referenced to GND)

4. $-55^{\circ}C \le T_{J} \le +125^{\circ}C$ 5. All outputs loaded; thresholds on input associated with output under test. 6. Test time 1sec max, measurement made by forcing indicated current and measuring voltage to minimize power dissipation. Test verifies a minimum 75 Ω transmission-line drive capability at 125°C





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DC Electrical Characteristics Continued (Voltages referenced to GND)

PARAMETER	SYMBOL			LIMITS			UNITS
	OTHEOL	•00	CONDITIONO	25°C	85°C	FULL RANGE	
		4.5V	Ι _{ουτ} = 50μΑ	4.4	4.4	4.4	V
Minimum High-Level	V _{OH}	5.5V	1001 – 90µA	5.4	5.4	5.4	V
Output Voltage	V OH	4.5V	$V_{IN} = V_{IL} \text{ or } V_{IH}^{5}$	3.86	3.76	9.7	V
	Γ	5.5V	I _{ОН} = -24mA	4.86	4.76	4.7	V
Maximum Input Leakage Current	I _{IN}	5.5V	$V_{IN} = V_{CC}$ or GND	±0.1	±1.0	±1.0	μA
Additional Maximum I _{CC} / Input	ΔI _{CCT}	5.5V	$V_{IN} = V_{CC} - 2.1V$	0.6	1.5	1.6	mA
Minimum Dynamic	I _{OLD}	5.5V	V _{OLD} = 1.65V Max	-	5	50	mA
Output Current ⁷	I _{OHD}	5.5V	V _{OHD} = 3.85V Min		-75	-50	
Maximum Quiescent Supply Leakage Current	I _{cc}	5.5V	$V_{IN} = V_{CC}$ or GND $I_{OUT} = 0\mu A$	4	40	80	μΑ

7. Maximum test duration 2ms, one output loaded at a time.

AC Electrical Characteristics⁸ $v_{cc} = 5.07 \pm 0.5V$

PARAMETER	SYMBOL	Vaa		LIMITS			UNITS
	OTIMBOE			25°C	85°C	FULL RANGE ⁴	UNITS
Maximum Propagation Delay	t _{PLH}	5.0V	$C_L = 50 pF$,	9.5	10	14.6	
Input A or B to Output Y (Figure 1)	t _{PHL}	5.0V Input tr = tf =3.0ns		9.5	10.5	14.6	ns
Maximum Input		5.0V	T _J = 25°C		TYPIC	AL	pF
Capacitance		0.07	0.0V Tj = 20 O		4.5		
Power Dissipation	C _{PD}	5.0V	T _J = 25°C,		35		pF
Capacitance	O PD	0.01	$C_L = 50 pF$	33			pr

8. Not production tested in die form, characterized by chip design.

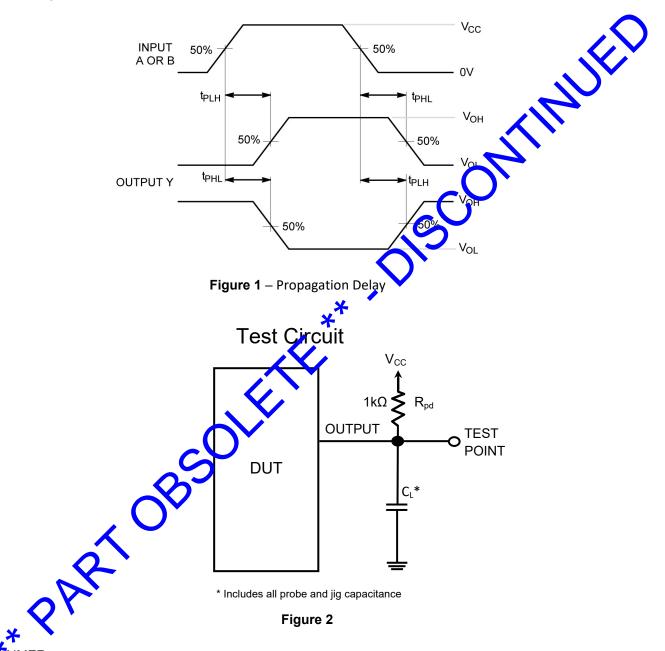


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Switching Waveform

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